

/ Descriptions

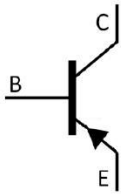
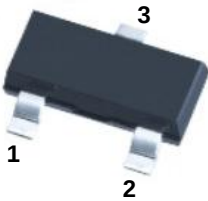
Silicon PNP transistor in a SOT-23 Plastic Package.

/ Features

High I_C , complementary pair with BC817.

/ Applications

General power amplifier and switching applications

/ Equivalent Circuit**/ Pinning**

PIN1 Base PIN 2 Emitter PIN 3 Collector

/ h_{FE} Classifications & Marking

h_{FE} Classifications Symbol	16	25	40
h_{FE} Range	100~250	160~400	250~600
Marking	H5A	H5B	H5C


/ Absolute Maximum Ratings(Ta=25)

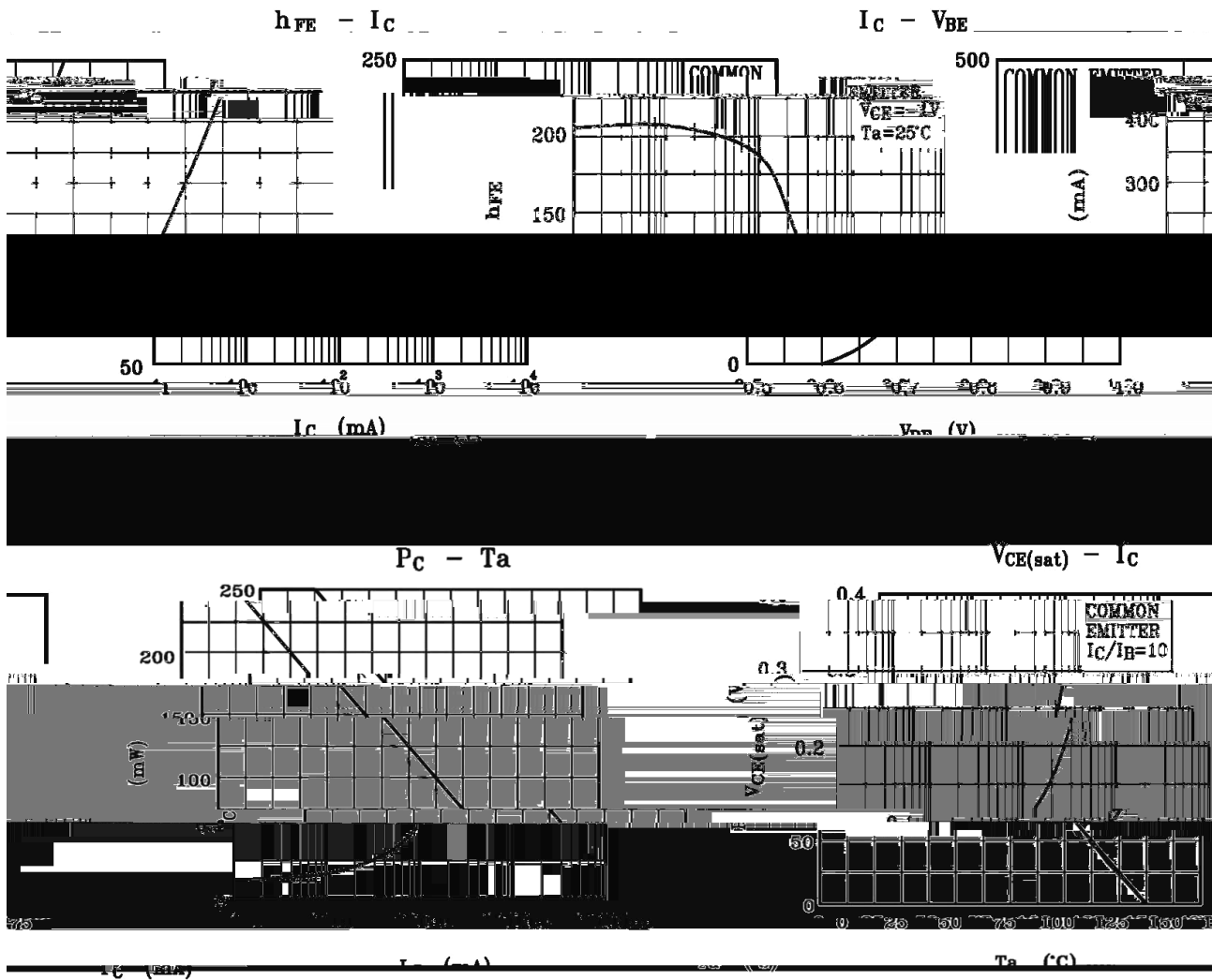
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-50	V
Collector to Emitter Voltage	V_{CEO}	-45	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-500	mA
Peak Collector Current - Continuous	I_{CM}	-1.0	A
Power Dissipation	P_C	250	mW
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55~150	

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Base Breakdown Voltage	V_{CBO}	$I_C = -10\mu A$ $I_E = 0$	-50			V
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C = -10mA^*$ $I_B = 0$	-45			V
Emitter to Base Breakdown Voltage	V_{EBO}	$I_E = -10\mu A$ $I_C = 0$	-5.0			V
Collector Cut-Off Current	I_{CBO}	$V_{CB} = -20V$ $I_E = 0$			-0.1	μA
Emitter Cut-Off Current	I_{EBO}	$V_{EB} = -5.0V$ $I_C = 0$			-0.1	μA
DC Current Gain	$h_{FE(1)}$	$V_{CE} = -1.0V$ $I_C = -100mA$	100		600	
	$h_{FE(2)}$	$V_{CE} = -1.0V$ $I_C = -500mA^*$	40			
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -500mA$ $I_B = -50mA^*$			-0.7	V
Base to Emitter Voltage	V_{BE}	$V_{CE} = -1.0V$ $I_C = -500mA$			-1.2	V
Transition Frequency	f_T	$V_{CE} = -5V$ $I_C = -10mA$	80			MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = -10V$ $f = 1.0MHz$ $I_E = 0$		9.0		pF

*pulse test: pulse width $\leq 300\mu S$, duty cycle $\leq 2.0\%$.

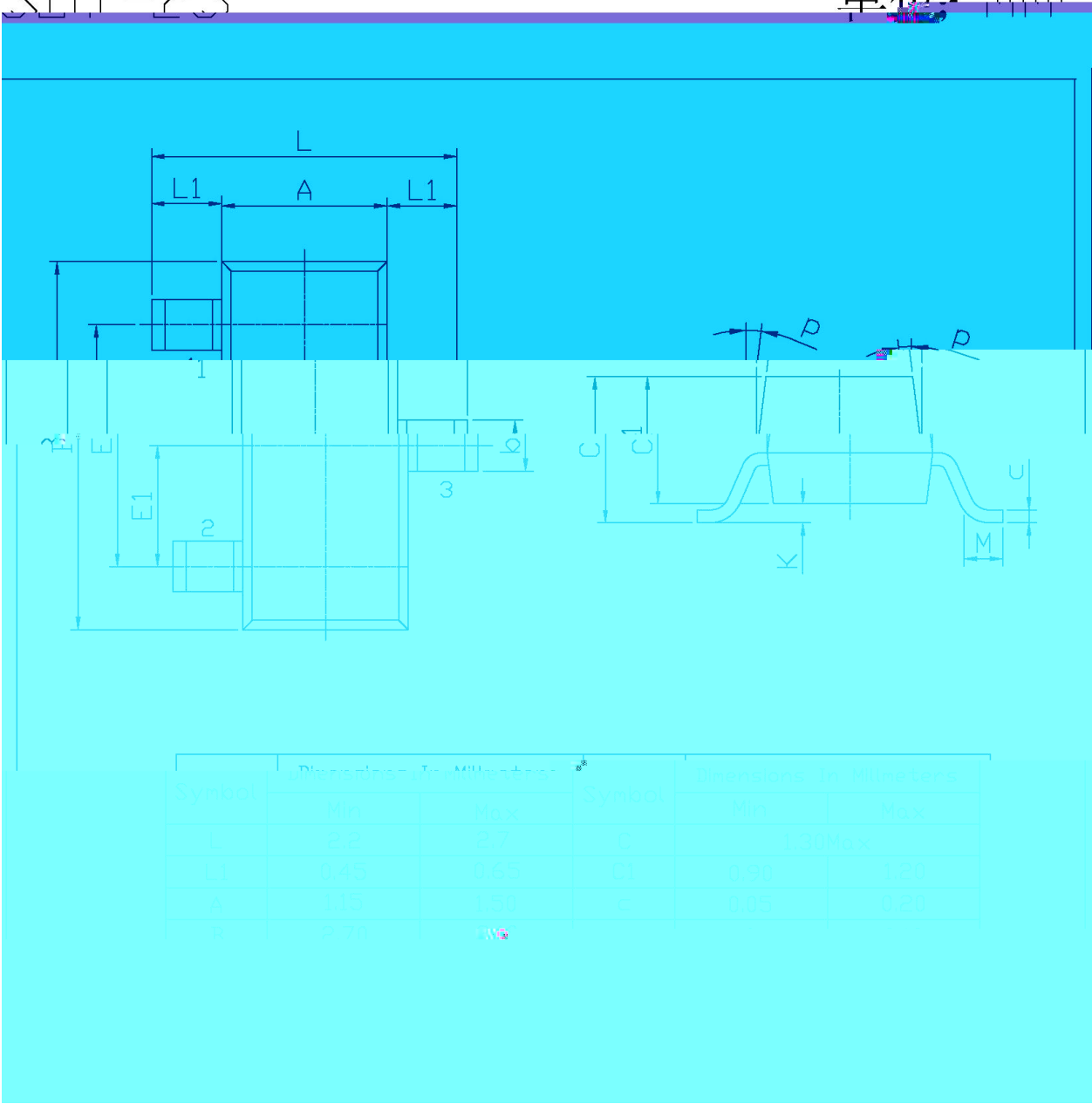
/ Electrical Characteristic Curve



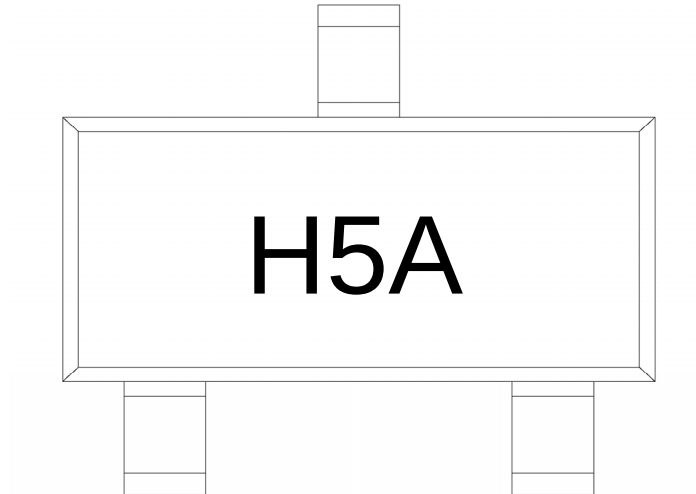
/ Package Dimensions

SOT-23

单位: mm



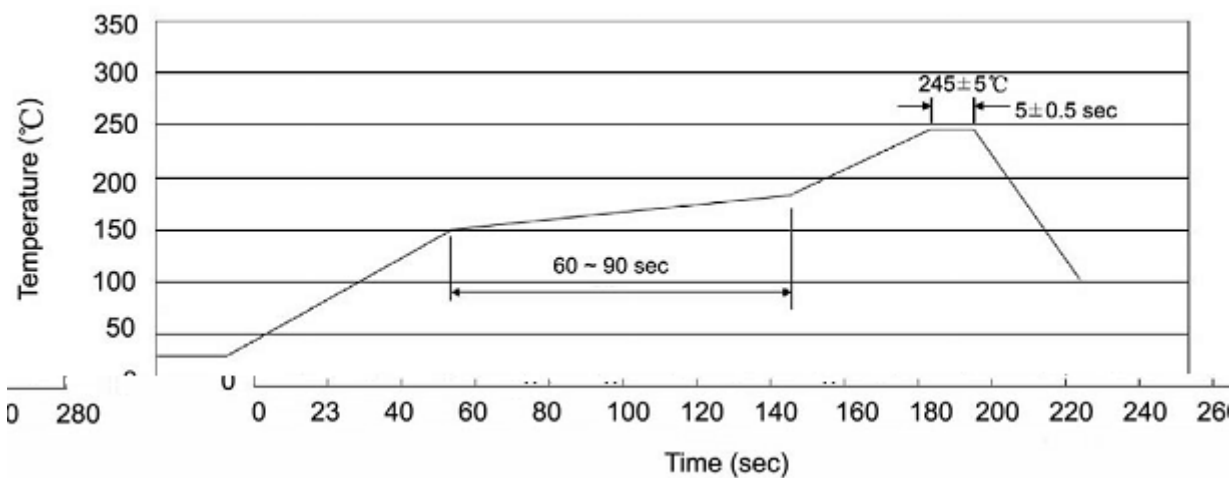
/ Marking Instructions



Note:

H: Company Code.

5A: Product Type Code


() / Temperature Profile for IR Reflow Soldering(Pb-Free)


Note:

- | | | | | | |
|---|-----|-----|----|----------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 245 | 5 | 5 | 0.5sec; | 2.Peak Temp.:245 5 , Duration:5 0.5sec. |
| 3 | | | 2 | 10 /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

260 ± 5 10 ± 1 sec. Temp.:260±5 Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	只 卷盘	卷盘 盒	只 盒	盒 箱	只 箱		盒	箱
						"		

/ Notices